

High Speed IGBT4 Modules

SKM100GAL12F4

Features*

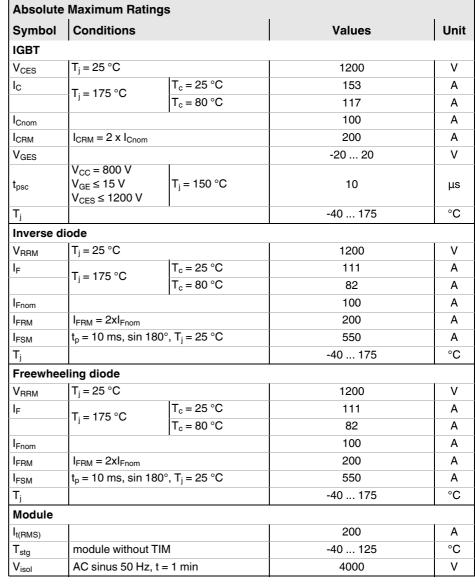
- · High speed trench and field-stop IGBT
- CAL4 ultra-fast = soft switching 4. generation CAL-diode
- Insulated copper baseplate using DBC technology (Direct Bonded Copper)
- · Increased power cycling capability
- For higher switching frequencies above 15kHz
- UL recognized, file no. E63532

Typical Applications

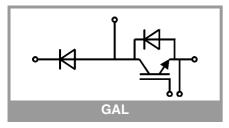
- · Electronic welders
- DC/DC converter
- Brake chopper
- · Switched reluctance motor

Remarks

- Case temperature limited to T_c = 125°C max.
- Recommended $T_{op} = -40 \dots +150$ °C
- Product reliability results valid for T_i = 150°C



Characteristics						
Symbol	Conditions		min.	typ.	max.	Unit
IGBT	•		·			
V _{CE(sat)}	I _C = 100 A	T _j = 25 °C		2.05	2.38	V
	V _{GE} = 15 V chiplevel	T _j = 150 °C		2.55	2.93	V
V _{CE0}	chiplevel	T _j = 25 °C		1.10	1.28	V
		T _j = 150 °C		0.95	1.13	V
r _{CE}	V _{GE} = 15 V chiplevel	T _j = 25 °C		9.5	11	mΩ
		T _j = 150 °C		16	18	mΩ
$V_{GE(th)}$	$V_{GE}=V_{CE}$, $I_{C}=3.8$ mA		5.1	5.8	6.4	V
I _{CES}	V _{GE} = 0 V V _{CE} = 1200 V	T _j = 25 °C			1	mA
		T _j = 150 °C		-		mA
C _{ies}	V _{CE} = 25 V V _{GE} = 0 V	f = 1 MHz		6.2		nF
Coes		f = 1 MHz		0.41		nF
C _{res}		f = 1 MHz		0.35		nF
Q_{G}	V _{GE} = - 8 V+ 15 V			567		nC
R _{Gint}	T _j = 25 °C			0		Ω





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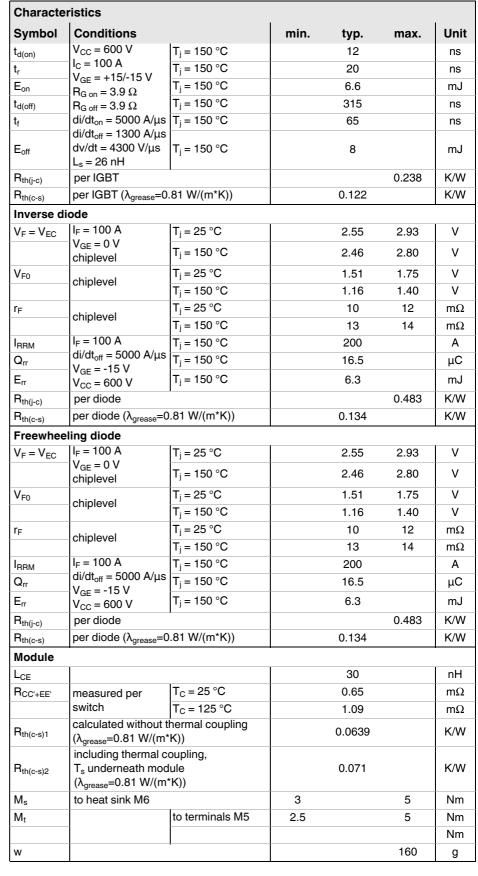
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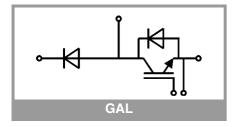
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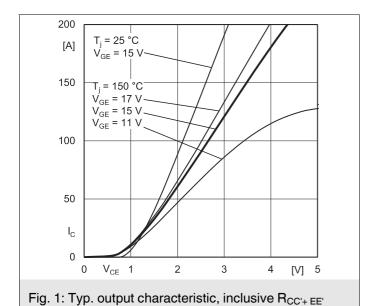
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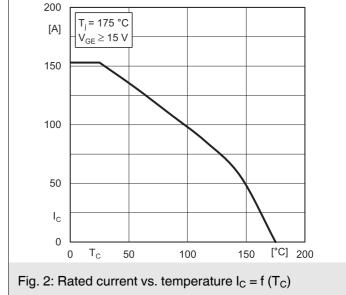
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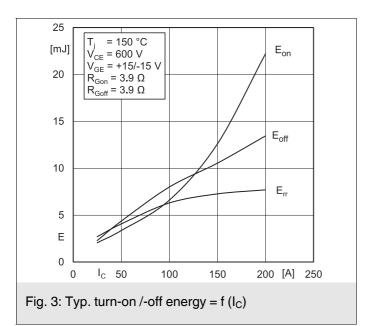
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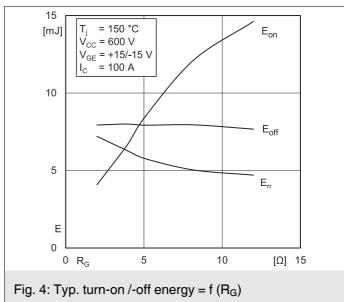


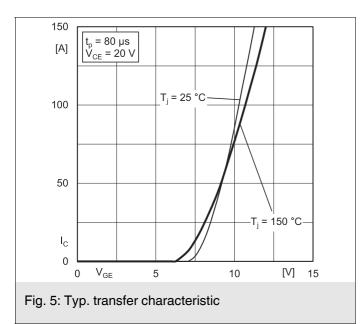


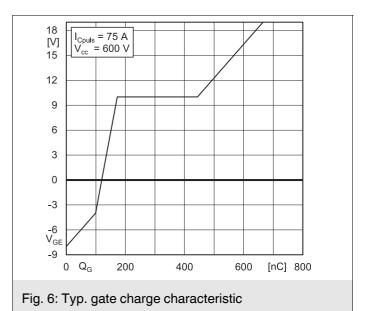


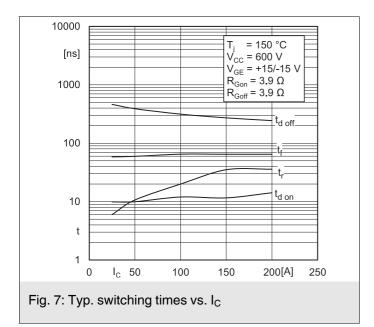


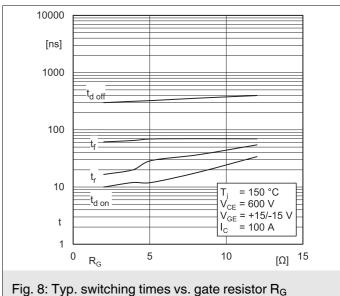


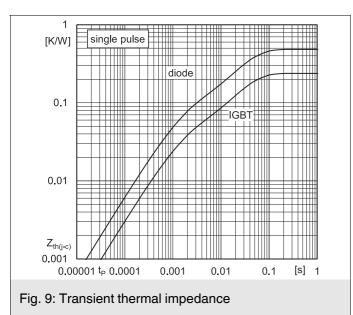


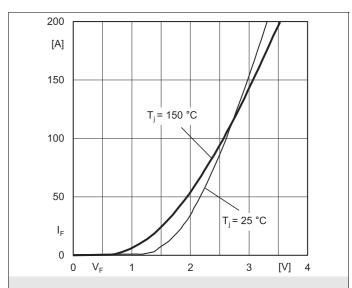


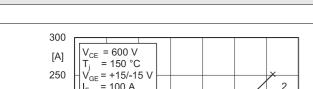


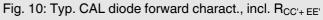


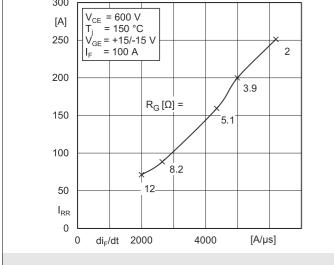












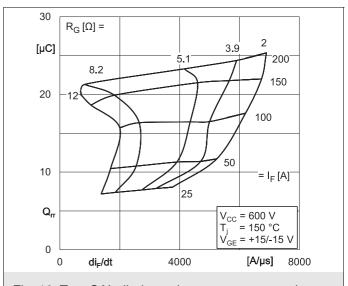
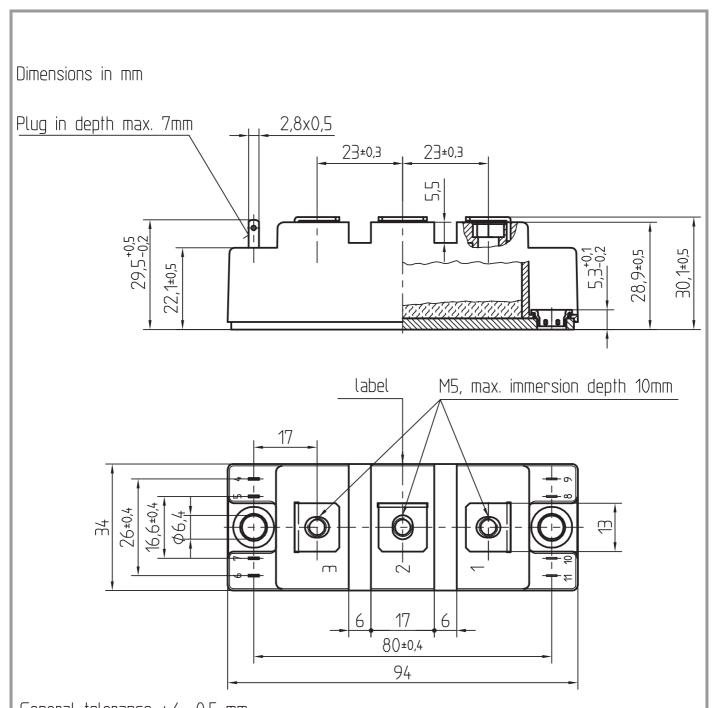
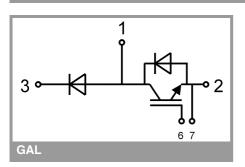


Fig. 11: Typ. CAL diode peak reverse recovery current



General tolerance +/- 0,5 mm

SEMITRANS 2



This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

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